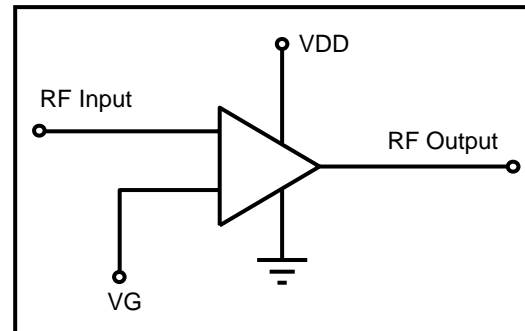


2-20GHz BROADBAND MMIC AMPLIFIER
FEATURES:

- 23 dBm Output Power
- 11dB Gain
- pHEMT Technology
- Input Return Loss < -8dB
- Output Return Loss < -10dB

GENERAL DESCRIPTION:

The FMA3008 is a high performance 2-20GHz Gallium Arsenide monolithic travelling wave amplifier. It is suitable for use in broadband communication, instrumentation and electronic warfare applications. The die is fabricated using the Filtronic 0.25 μ m process. The amplifier is DC blocked at both the input and output.

FUNCTIONAL SCHEMATIC:

TYPICAL APPLICATIONS:

- Test Instrumentation
- Electronic Warfare
- Broadband Communication Infrastructure

ELECTRICAL SPECIFICATIONS:

PARAMETER	CONDITIONS ^{1, 2, 3}	MIN	TYP	MAX	UNITS
Small Signal Gain	2-12GHz	10	11	11.5	dB
Small Signal Gain	12-20GHz	11	12	13.5	dB
Input Return Loss	2-20GHz	-	-10	-8	dB
Output Return Loss	2-20GHz	-	-15	-10	dB
Reverse Isolation	2-20GHz	-	< -30	-23	dB
Output Power at 1dB compression point	2GHz	18	23.5	-	dBm
	10GHz	16.5	23.5	-	dBm
	20GHz	16	20	-	dBm
Noise Figure	2 - 4.5 GHz	-	-	8	dB
Noise Figure	4.5 - 20GHz	-	4.5	6.5	dB
Drain Current	For Vg = -0.28V	90	140	160	mA
Drain Voltage		-	7.0	-	V

Notes:

1. T_{Ambient} = +25°C
2. Device is biased at constant gate voltage, measured on wafer with Z₀ = 50 Ω
3. Measurement Conditions VG= -0.28V, VDD= 7V

ABSOLUTE MAXIMUM RATINGS:

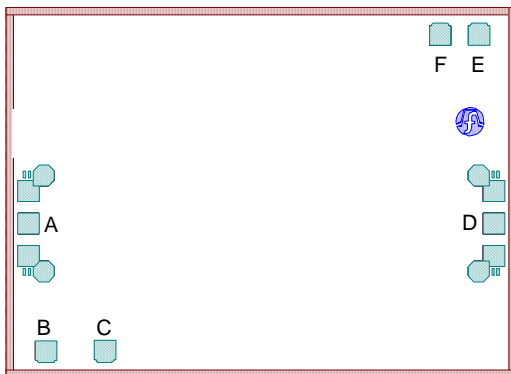
PARAMETER	SYMBOL	ABSOLUTE MAXIMUM
Max Input Power	Pin	+20dBm
Gate Voltage	VG1	-2V
Drain Voltage	VDD	+10V
Total Power Dissipation	Ptot	tbd
Gain Compression	Comp	tbd
Thermal Resistivity	θ_{JC}	38°C/W
Operating Temp	Toper	-40°C to +85°C
Storage Temp	Tstor	-55°C to +150°C

PAD LAYOUT:

PAD REF	PAD NAME	DESCRIPTION	PIN COORDINATES (μm)
A	RF in	RF in	(105, 713)
B	GND	Ground	(198, 126)
C	VG	Gate Voltage	(461, 128)
D	Out	RF Output	(663, 713)
E	GND	Ground	(2170, 1580)
F	VD	Drain Voltage	(1998, 1580)

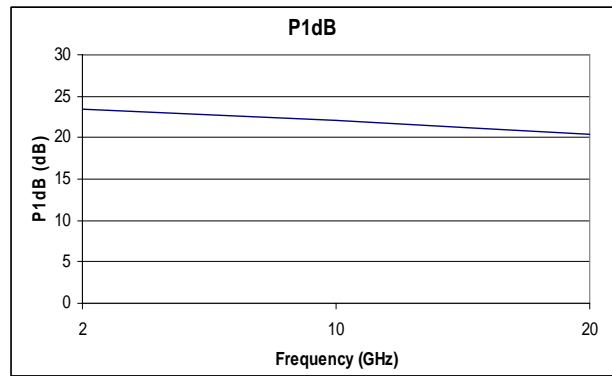
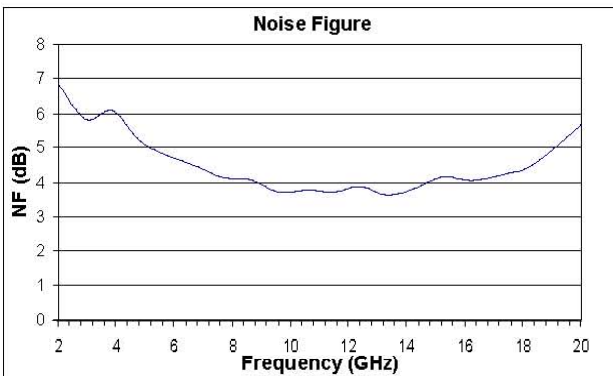
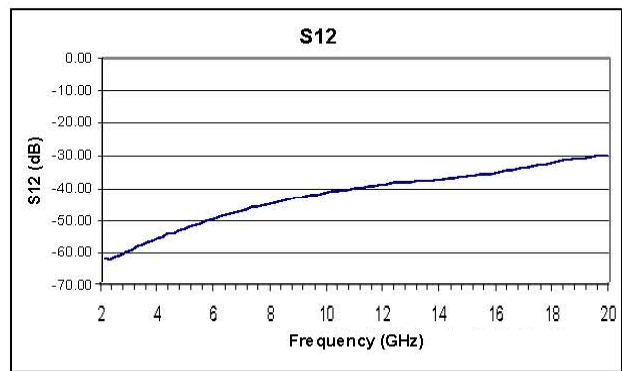
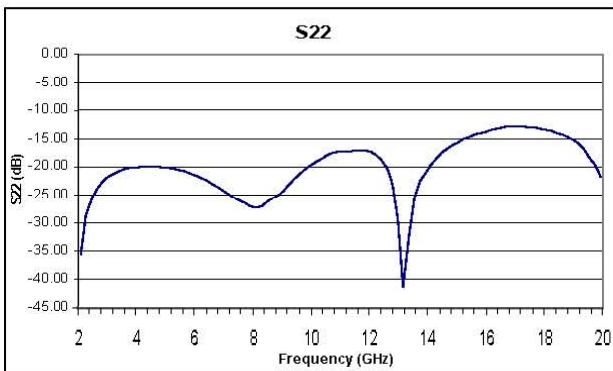
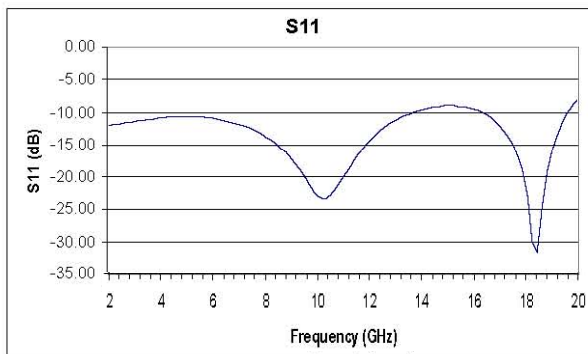
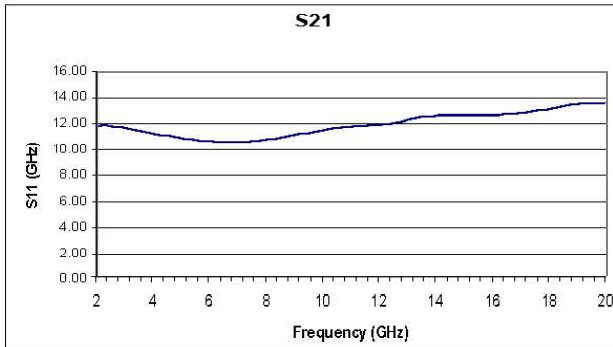
Note: Co-ordinates are referenced from the bottom left hand corner of the die to the centre of bond pad opening

Note: Exceeding any one of these absolute maximum ratings may cause permanent damage to the device.

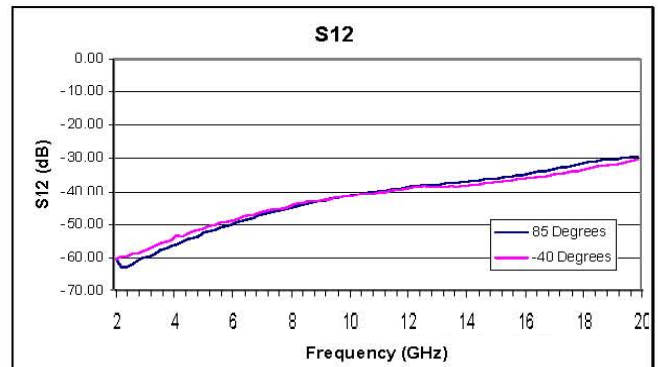
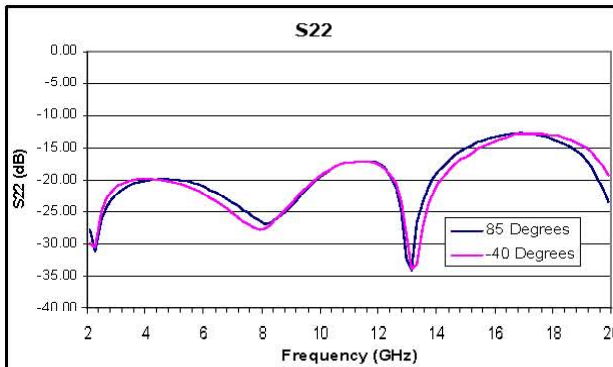
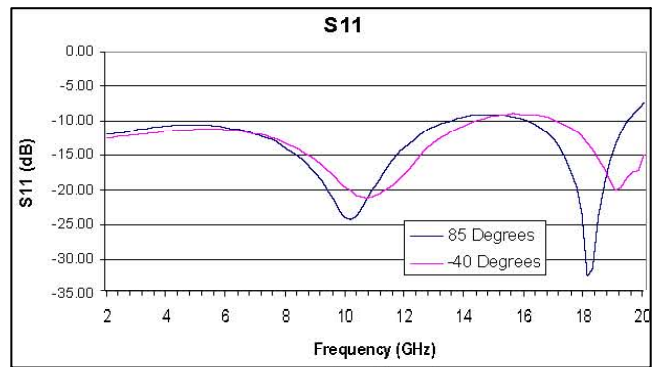
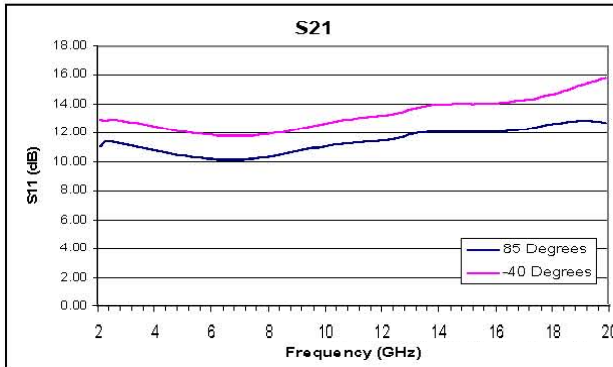


DIE SIZE (μm)	DIE THICKNESS (μm)	MIN. BOND PAD PITCH (μm)	MIN. BOND PAD OPENING ($\mu\text{m} \times \mu\text{m}$)
2350 x 1710	100	179	100 x 100

TYPICAL PERFORMANCE FOR ON WAFER MEASUREMENTS:

 Note: Measurement Conditions $V_G = -0.28V$, $V_{DD} = 7V$, $T_{AMBIENT} = 25^\circ C$


TYPICAL MEASURED PERFORMANCE FOR ON WAFER TEMPERATURE MEASUREMENTS:

 Note: Measurement Conditions $V_G = -0.28V$, $V_{DD} = 7V$, $T_{AMBIENT} = -40^{\circ}C$ to $+85^{\circ}C$


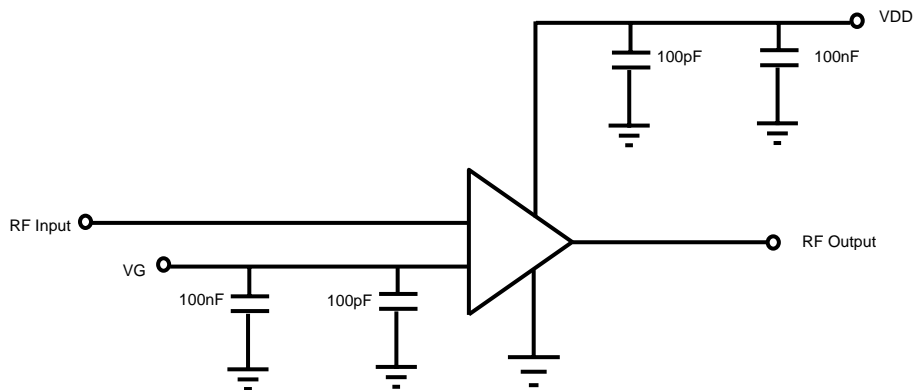
S-PARAMETERS FOR ON WAFER MEASUREMENTS:

 Note: Measurement Conditions $V_G = -0.28V$, $V_{DD} = 7V$.

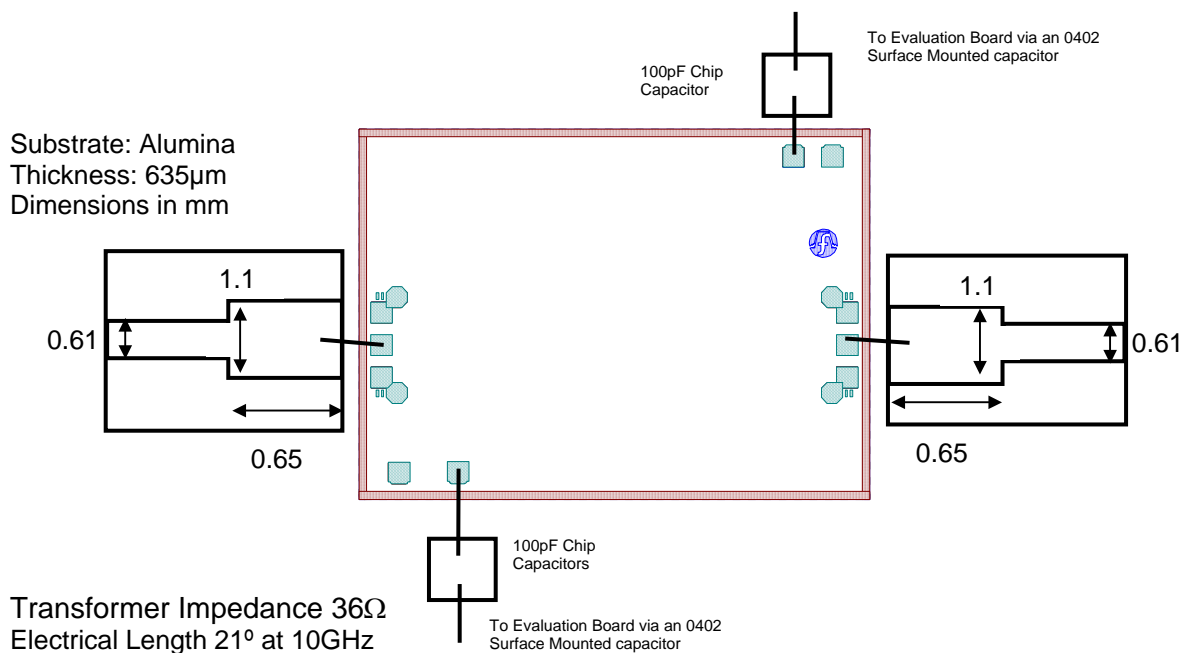
Frequency	S11		S21		S12		S22	
	Mag	Angle	Mag	Angle	Mag	Angle	Mag	Angle
2	0.25	43.20	0.25	43.20	0.25	43.20	0.25	43.12
2.19	0.25	39.39	0.25	39.39	0.25	39.39	0.25	39.31
2.38	0.26	35.85	0.26	35.85	0.26	35.85	0.26	35.77
2.57	0.26	32.34	0.26	32.34	0.26	32.34	0.26	32.27
2.76	0.26	28.94	0.26	28.94	0.26	28.94	0.26	28.86
2.95	0.27	25.69	0.27	25.69	0.27	25.69	0.27	25.60
3.14	0.27	22.45	0.27	22.45	0.27	22.45	0.27	22.36
3.33	0.28	19.13	0.28	19.13	0.28	19.13	0.28	19.05
3.52	0.28	15.98	0.28	15.98	0.28	15.98	0.28	15.89
3.71	0.28	12.78	0.28	12.78	0.28	12.78	0.28	12.71
3.9	0.29	9.46	0.29	9.46	0.29	9.46	0.29	9.39
4.09	0.29	6.29	0.29	6.29	0.29	6.29	0.29	6.22
4.28	0.29	3.02	0.29	3.02	0.29	3.02	0.29	2.95
4.47	0.29	-0.34	0.29	-0.34	0.29	-0.34	0.29	-0.39
4.66	0.29	-3.65	0.29	-3.65	0.29	-3.65	0.29	-3.70
4.85	0.29	-6.96	0.29	-6.96	0.29	-6.96	0.29	-7.03
5.04	0.29	-10.37	0.29	-10.37	0.29	-10.37	0.29	-10.44
5.23	0.29	-13.76	0.29	-13.76	0.29	-13.76	0.29	-13.81
5.42	0.29	-17.11	0.29	-17.11	0.29	-17.11	0.29	-17.17
5.61	0.29	-20.57	0.29	-20.57	0.29	-20.57	0.29	-20.62
5.8	0.29	-24.15	0.29	-24.15	0.29	-24.15	0.29	-24.20
5.99	0.28	-27.59	0.28	-27.59	0.28	-27.59	0.28	-27.63
6.18	0.28	-31.36	0.28	-31.36	0.28	-31.36	0.28	-31.41
6.37	0.28	-35.15	0.28	-35.15	0.28	-35.15	0.28	-35.19
6.56	0.27	-38.98	0.27	-38.98	0.27	-38.98	0.27	-39.02
6.75	0.27	-42.83	0.27	-42.83	0.27	-42.83	0.27	-42.87
6.94	0.26	-46.73	0.26	-46.73	0.26	-46.73	0.26	-46.77
7.13	0.25	-50.63	0.25	-50.63	0.25	-50.63	0.25	-50.67
7.32	0.24	-54.69	0.24	-54.69	0.24	-54.69	0.24	-54.74
7.51	0.23	-59.03	0.23	-59.03	0.23	-59.03	0.23	-59.07
7.7	0.23	-63.47	0.23	-63.47	0.23	-63.47	0.23	-63.49
7.89	0.21	-68.15	0.21	-68.15	0.21	-68.15	0.21	-68.19
8.08	0.20	-72.89	0.20	-72.89	0.20	-72.89	0.20	-72.91
8.27	0.19	-78.03	0.19	-78.03	0.19	-78.03	0.19	-78.05
8.46	0.18	-83.18	0.18	-83.18	0.18	-83.18	0.18	-83.23
8.65	0.17	-88.76	0.17	-88.76	0.17	-88.76	0.17	-88.79
8.84	0.15	85.32	0.15	85.32	0.15	85.32	0.15	85.28
9.03	0.14	78.70	0.14	78.70	0.14	78.70	0.14	78.66
9.22	0.13	71.12	0.13	71.12	0.13	71.12	0.13	71.08
9.41	0.11	62.64	0.11	62.64	0.11	62.64	0.11	62.61
9.6	0.10	52.12	0.10	52.12	0.10	52.12	0.10	51.99
9.79	0.08	40.06	0.08	40.06	0.08	40.06	0.08	39.94
9.98	0.07	24.48	0.07	24.48	0.07	24.48	0.07	24.35
10.17	0.07	5.78	0.07	5.78	0.07	5.78	0.07	5.64
10.36	0.07	-15.15	0.07	-15.15	0.07	-15.15	0.07	-15.29
10.55	0.07	-36.45	0.07	-36.45	0.07	-36.45	0.07	-36.55
10.74	0.08	-54.27	0.08	-54.27	0.08	-54.27	0.08	-54.38
10.93	0.09	-69.24	0.09	-69.24	0.09	-69.24	0.09	-69.28

S-PARAMETERS CONTINUED

Frequency	S11		S21		S12		S22	
	Mag	Angle	Mag	Angle	Mag	Angle	Mag	Angle
11.12	0.11	-81.40	0.11	-81.40	0.11	-81.40	0.11	-81.40
11.31	0.12	52.68	0.12	52.68	0.12	52.68	0.12	52.62
11.5	0.14	80.39	0.14	80.39	0.14	80.39	0.14	80.37
11.69	0.16	72.58	0.16	72.58	0.16	72.58	0.16	72.57
11.88	0.18	65.41	0.18	65.41	0.18	65.41	0.18	65.40
12.07	0.20	58.92	0.20	58.92	0.20	58.92	0.20	58.93
12.26	0.21	52.93	0.21	52.93	0.21	52.93	0.21	52.96
12.45	0.23	47.30	0.23	47.30	0.23	47.30	0.23	47.36
12.64	0.25	41.82	0.25	41.82	0.25	41.82	0.25	41.87
12.83	0.26	36.47	0.26	36.47	0.26	36.47	0.26	36.54
13.02	0.28	31.06	0.28	31.06	0.28	31.06	0.28	31.14
13.21	0.29	25.89	0.29	25.89	0.29	25.89	0.29	25.96
13.4	0.30	20.96	0.30	20.96	0.30	20.96	0.30	21.04
13.59	0.31	15.93	0.31	15.93	0.31	15.93	0.31	16.00
13.78	0.32	11.04	0.32	11.04	0.32	11.04	0.32	11.15
13.97	0.33	6.08	0.33	6.08	0.33	6.08	0.33	6.16
14.16	0.34	1.08	0.34	1.08	0.34	1.08	0.34	1.19
14.35	0.34	-3.80	0.34	-3.80	0.34	-3.80	0.34	-3.68
14.54	0.35	-8.44	0.35	-8.44	0.35	-8.44	0.35	-8.32
14.73	0.35	-12.99	0.35	-12.99	0.35	-12.99	0.35	-12.89
14.92	0.36	-17.67	0.36	-17.67	0.36	-17.67	0.36	-17.55
15.11	0.36	-22.44	0.36	-22.44	0.36	-22.44	0.36	-22.32
15.3	0.35	-27.66	0.35	-27.66	0.35	-27.66	0.35	-27.51
15.49	0.35	-32.82	0.35	-32.82	0.35	-32.82	0.35	-32.67
15.68	0.35	-37.57	0.35	-37.57	0.35	-37.57	0.35	-37.42
15.87	0.34	-42.54	0.34	-42.54	0.34	-42.54	0.34	-42.40
16.06	0.33	-47.81	0.33	-47.81	0.33	-47.81	0.33	-47.65
16.25	0.33	-52.82	0.33	-52.82	0.33	-52.82	0.33	-52.65
16.44	0.31	-58.18	0.31	-58.18	0.31	-58.18	0.31	-57.99
16.63	0.30	-63.88	0.30	-63.88	0.30	-63.88	0.30	-63.68
16.82	0.28	-69.25	0.28	-69.25	0.28	-69.25	0.28	-69.04
17.01	0.26	-74.77	0.26	-74.77	0.26	-74.77	0.26	-74.53
17.2	0.23	-80.74	0.23	-80.74	0.23	-80.74	0.23	-80.46
17.39	0.21	-86.96	0.21	-86.96	0.21	-86.96	0.21	-86.66
17.58	0.18	50.66	0.18	50.66	0.18	50.66	0.18	50.98
17.77	0.15	78.36	0.15	78.36	0.15	78.36	0.15	78.72
17.96	0.11	69.56	0.11	69.56	0.11	69.56	0.11	70.01
18.15	0.07	58.88	0.07	58.88	0.07	58.88	0.07	59.64
18.34	0.03	30.46	0.03	30.46	0.03	30.46	0.03	33.13
18.53	0.03	-25.89	0.03	-25.89	0.03	-25.89	0.03	-23.99
18.72	0.06	70.21	0.06	70.21	0.06	70.21	0.06	70.75
18.91	0.11	56.90	0.11	56.90	0.11	56.90	0.11	57.25
19.1	0.16	47.25	0.16	47.25	0.16	47.25	0.16	47.65
19.29	0.21	38.16	0.21	38.16	0.21	38.16	0.21	38.57
19.48	0.26	30.13	0.26	30.13	0.26	30.13	0.26	30.57
19.67	0.31	22.29	0.31	22.29	0.31	22.29	0.31	22.68
19.86	0.35	14.93	0.35	14.93	0.35	14.93	0.35	15.36
20	0.39	7.63	0.39	7.63	0.39	7.63	0.39	8.08

BIASING CIRCUIT SCHEMATIC:

ASSEMBLY DIAGRAM:

It is recommended that the RF connections be made using two bond wires 25 μ m in diameter and a maximum length of 300 μ m. Optimum input and output return loss can be achieved, to compensate for bond wire length, with the addition of a microstrip transformer, shown in the diagram below.


BILL OF MATERIALS:

COMPONENT
All RF tracks should be 50 Ω characteristic material
Capacitor, 100pF, chip capacitor
Capacitor, 100pF, 0402

PREFERRED ASSEMBLY INSTRUCTIONS:

GaAs devices are fragile and should be handled with great care. Specially designed collets should be used where possible.

The recommended die attach is gold/tin eutectic solder under a nitrogen atmosphere. Stage temperature should be 280-290°C; maximum time at temperature is one minute. The recommended wire bond method is thermo-compression wedge bonding with 0.7 or 1.0 mil (0.018 or 0.025 mm) gold wire. Stage temperature should be 250-260°C.

Bonds should be made from the die first and then to the mounting substrate or package. The physical length of the bondwires should be minimised especially when making RF or ground connections.

ORDERING INFORMATION:

PART NUMBER	DESCRIPTION
FMA3008	Die in Waffle-pack (Gel-pak available on request)

HANDLING PRECAUTIONS:


To avoid damage to the devices care should be exercised during handling. Proper Electrostatic Discharge (ESD) precautions should be observed at all stages of storage, handling, assembly, and testing. These devices should be treated as Class 0 (0-250 V) as defined in JEDEC Standard No. 22-A114. Further information on ESD control measures can be found in MIL-STD-1686 and MIL-HDBK-263.

APPLICATION NOTES & DESIGN DATA:

Application Notes and design data including S-parameters, noise data are available on request.

DISCLAIMERS:

This product is not designed for use in any space based or life sustaining/supporting equipment.